

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor dates sheds, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor dates sheds and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use on similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor and its officers, employees, subsidiaries, affliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out or i, directly or indirectly, any lay bed ON Semiconductor and its officers, employees, ween if such claim alleges that ON Semiconductor was negligent regarding the d

July 2010

FAN7621S PFM Controller for Half-Bridge Resonant Converters

Features

FAIRCHILD

SEMICONDUCTOR

- Variable Frequency Control with 50% Duty Cycle for Half-bridge Resonant Converter Topology
- High Efficiency through Zero Voltage Switching (ZVS)
- Fixed Dead Time: 350ns
- Up to 300kHz Operating Frequency
- Auto-Restart Operation for All Protections with an External LV_{CC}
- Protection Functions: Over-Voltage Protection (OVP), Over-Current Protection (OCP), Abnormal Over-Current Protection (AOCP), Internal Thermal Shutdown (TSD)

Applications

- PDP and LCD TVs
- Desktop PCs and Servers
- Adapters
- Telecom Power Supplies
- Video Game Consoles

Description

The FAN7621S is a pulse frequency modulation controller for high-efficiency half-bridge resonant converters. Offering everything necessary to build a reliable and robust resonant converter, the FAN7621S simplifies designs and improves productivity, while improving performance. The FAN7621S includes a highside gate-drive circuit, an accurate current-controlled oscillator, frequency-limit circuit, soft-start, and built-in protection functions. The high-side gate-drive circuit has a common-mode noise cancellation capability, which guarantees stable operation with excellent noise immunity. Using the zero-voltage-switching (ZVS) technique dramatically reduces the switching losses and significantly improves efficiency. The ZVS also reduces the switching noise noticeably, which allows a smallsized Electromagnetic Interference (EMI) filter.

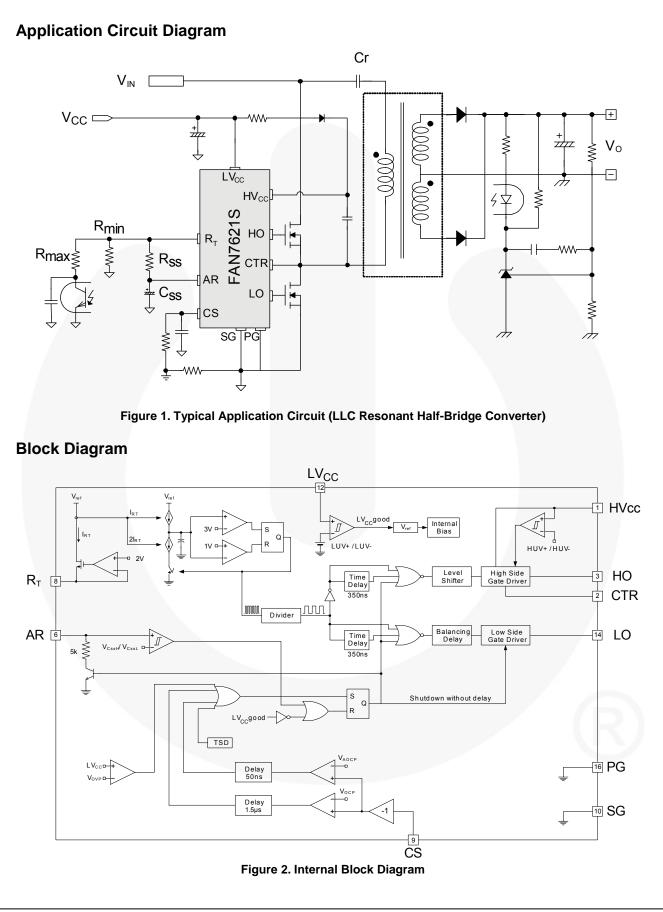
The FAN7621S can be applied to various resonant converter topologies; such as series resonant, parallel resonant, and LLC resonant converters.

Related Resources

<u>AN4151 — Half-Bridge LLC Resonant Converter Design</u> <u>Using FSFR-Series Fairchild Power Switch (FPSTM)</u>

Ordering Information

Part Number	Operating Junction Temperature	Package	Packaging Method
FAN7621SSJ	-40°C to +130°C	16-Lead, Small Outline Package (SOP)	Tube
FAN7621SSJX	-40°C 10 +130°C	To-Lead, Small Outline Fackage (SOF)	Tape & Reel



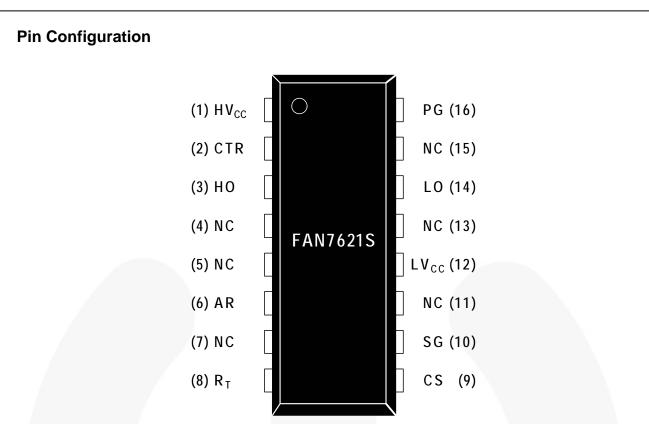


Figure 3. Package Diagram

Pin Definitions

Pin #	Name	Description	
1	HVcc	This is the supply voltage of the high-side gate-drive circuit IC.	
2	CTR	This is the drain of the low-side MOSFET. Typically, a transformer is connected to this pin.	
3	HO	This is the high-side gate driving signal.	
4	NC	No connection	
5	NC	No connection	
6	AR	This pin is for discharging the external soft-start capacitor when any protection is triggered. When the voltage of this pin drops to 0.2V, all protections are reset and the controller starts to operate again.	
7	NC	No connection	
8	RT	This pin programs the switching frequency. Typically, an opto-coupler is connected to cont the switching frequency for the output voltage regulation.	
9	CS	This pin senses the current flowing through the low-side MOSFET. Typically, negative voltage is applied on this pin.	
10	SG	This pin is the control ground.	
11	NC	No connection	
12	LV _{CC}	This pin is the supply voltage of the control IC.	
13	NC	No connection	
14	LO	This is the low-side gate driving signal.	
15	NC	No connection	
16	PG	This pin is the power ground. This pin is connected to the source of the low-side MOSFET.	

FAN7621S — PFM Controller for Half-Bridge Resonant Converters

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. $T_A=25^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Min.	Max.	Unit
V _{HO}	High-Side Gate Driving Voltage	V _{CTR} -0.3	HVcc	V
V _{LO}	Low-Side Gate Driving Voltage	-0.3	LV _{CC}	v
LV _{CC}	Low-Side Supply Voltage	-0.3	25.0	V
HV_{CC} to V_{CTR}	High-Side V _{CC} Pin to Center Voltage	-0.3	25.0	V
V _{CTR}	Center Voltage	-0.3	600.0	V
V _{AR}	Auto-Restart Pin Input Voltage	-0.3	LV _{CC}	V
V _{CS}	Current Sense (CS) Pin Input Voltage	-5.0	1.0	V
V _{RT}	R⊤ Pin Input Voltage	-0.3	5.0	V
dV _{CTR} /dt	Allowable Center Voltage Slew Rate		50	V/ns
PD	Total Power Dissipation		1.13	W
Ŧ	Maximum Junction Temperature ⁽¹⁾		+150	•0
TJ	Recommended Operating Junction Temperature ⁽¹⁾	-40	+130	°C
T _{STG}	Storage Temperature Range	-55	+150	°C

Note:

1. The maximum value of the recommended operating junction temperature is limited by thermal shutdown.

Thermal Impedance

Symbol	Parameter	Value	Unit
θ _{JA}	Junction-to-Ambient Thermal Impedance	110	°C/W

Electrical Characteristics

 $T_A{=}25^\circ C$ and $LV_{CC}{=}17V$ unless otherwise specified.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Supply Sec	tion		•	•	•	
I _{LK}	Offset Supply Leakage Current	HV _{CC} =V _{CTR}			50	μA
I_QHV_{CC}	Quiescent HVcc Supply Current	(HV _{cc} UV+) - 0.1V		50	120	μA
I _Q LV _{CC}	Quiescent LVcc Supply Current	(LV _{CC} UV+) - 0.1V		100	200	μA
I ₀ HV _{cc}	Operating HV _{cc} Supply Current	f_{OSC} =100kHz, C _{Load} =1nF		5	8	mA
	(RMS Value)	No Switching		100	200	μA
I _o LV _{cc}	Operating LV _{cc} Supply Current	f _{OSC} =100kHz, C _{Load} =1nF		6	9	mA
102000	(RMS Value)	No Switching		2	4	mA
UVLO Secti	on					
LV _{CC} UV+	LV _{CC} Supply Under-Voltage Positive-	Going Threshold (LV _{CC} Start)	11.2	12.5	13.8	V
LV _{CC} UV-	LV _{CC} Supply Under-Voltage Negative	-Going Threshold (LV _{CC} Stop)	8.9	10.0	11.1	V
LV _{cc} UVH	LV _{CC} Supply Under-Voltage Hysteres	is		2.5		V
HV _{cc} UV+	HV _{CC} Supply Under-Voltage Positive-	-Going Thresho <mark>ld (HV_{CC} Start)</mark>	8.2	9.2	10.2	V
HVccUV-	HVcc Supply Under-Voltage Negative-Going Threshold (HVcc		7.8	8.7	9.6	V
HV _{cc} UVH	HV _{cc} Supply Under-Voltage Hysteresis			0.5		V
Oscillator 8	Feedback Section				•	
V _{RT}	V-I Converter Threshold Voltage		1.5	2.0	2.5	V
f _{OSC}	Output Oscillation Frequency	R _T =5.2kΩ	94	100	106	kHz
DC	Output Duty Cycle		48	50	52	%
f _{SS}	Internal Soft-Start Initial Frequency	f _{SS} =f _{OSC} +40kHz, R _T =5.2kΩ		140		kHz
t _{ss}	Internal Soft-Start Time		2	3	4	ms
Output Sec	tion					7
Isource	Peak Sourcing Current	HV _{CC} =17V	250	360		mA
I _{sink}	Peak Sinking Current	HV _{CC} =17V	460	600		mA
tr	Rising Time			65		ns
t _f	Falling Time	C _{Load} =1nF, HV _{CC} =17V		35		ns
V _{HOH}	High Level of High-Side Gate Driving Signal (V _{HVCC} -V _{HO})				1.0	v
V _{HOL}	Low Level of High-Side Gate Driving Signal				0.6	v
V _{LOH}	High Level of High-Side Gate Driving Signal (V _{LVCC} -V _{LO})	— I ₀ =20mA			1.0	v
V _{LOL}	Low Level of High-Side Gate Driving Signal				0.6	V
						·

Electrical Characteristics (Continued)

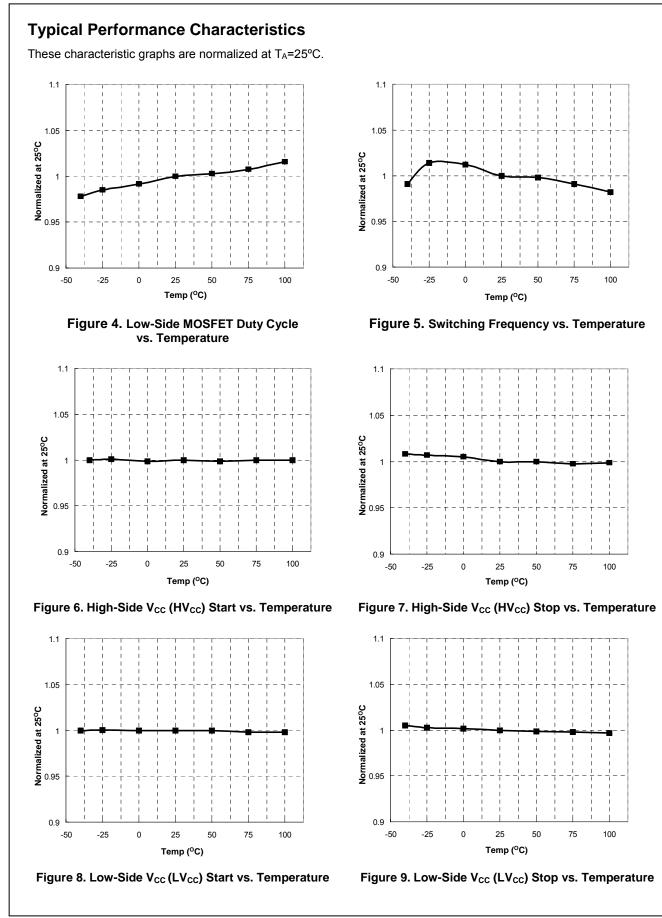
 $T_A {=} 25^{\circ} C$ and $LV_{CC} {=} 17 V$ unless otherwise specified.

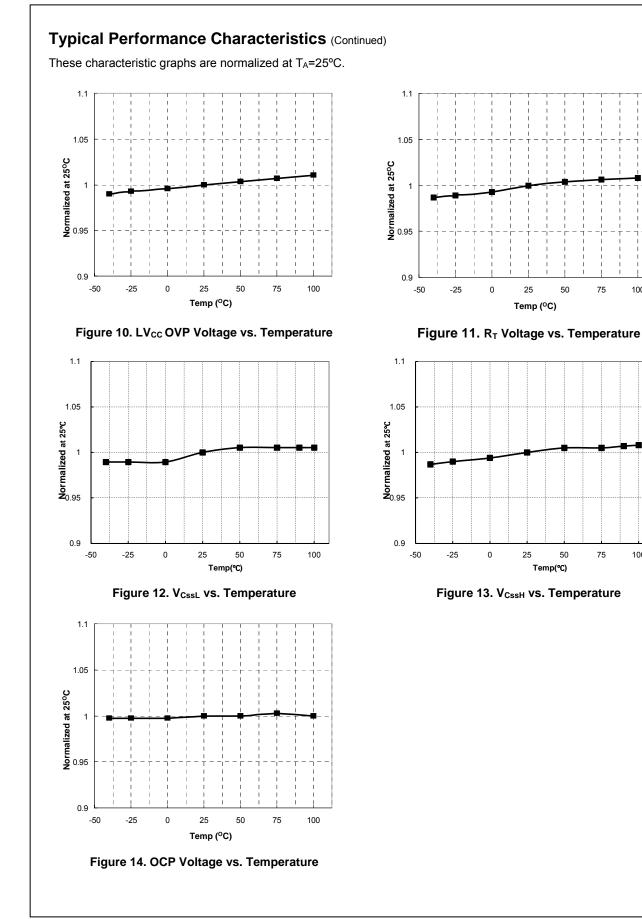
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Protection	Section				1	1
V_{CssH}	Beginning Voltage to Discharge Css		0.9	1.0	1.1	V
V _{CssL}	Beginning Voltage to Charge C _{SS} and Reset Protections		0.16	0.20	0.24	V
V _{OVP}	LV _{CC} Over-Voltage Protection	LV _{CC} > 21V	21	23	25	V
VAOCP	AOCP Threshold Voltage	∆V/∆t=-0.1V/µs	-1.0	-0.9	-0.8	V
t _{BAO}	AOCP Blanking Time ⁽²⁾	V _{CS} < V _{AOCP} ; ΔV/Δt=-0.1V/μs		50		ns
V _{OCP}	OCP Threshold Voltage	∆V/∆t=-1V/µs	-0.64	-0.58	-0.52	V
t _{BO}	OCP Blanking Time ⁽²⁾	V _{CS} < V _{OCP} ; ΔV/Δt=-1V/μs	1.0	1.5	2.0	μs
t _{DA}	Delay Time (Low-Side) Detecting from V_{AOCP} to Switch Off ⁽²⁾	ΔV/Δt=-1V/μs		250	400	ns
T _{SD}	Thermal Shutdown Temperature ⁽²⁾		110	130	150	°C
Dead-Time	Control Section					
DT	Dead Time ⁽³⁾			350		ns

Notes:

2. These parameters, although guaranteed, are not tested in production.

3. These parameters, although guaranteed, are tested only in EDS (wafer test) process.

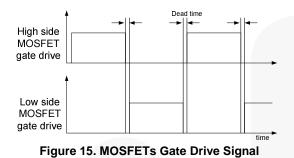




FAN7621S — PFM Controller for Half-Bridge Resonant Converters

Functional Description

1. Basic Operation: FAN7621S is designed to drive high-side and low-side MOSFETs complementarily with 50% duty cycle. A fixed dead time of 350ns is introduced between consecutive transitions, as shown in Figure 15.



2. Internal Oscillator: FAN7621S employs a currentcontrolled oscillator, as shown in Figure 16. Internally, the voltage of R_T pin is regulated at 2V and the charging / discharging current for the oscillator capacitor, C_T, is obtained by copying the current flowing out of R_T pin (I_{CTC}) using a current mirror. Therefore, the switching frequency increases as I_{CTC} increases.

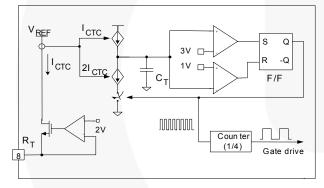


Figure 16. Current Controlled Oscillator

3. Frequency Setting: Figure 17 shows the typical voltage gain curve of a resonant converter, where the gain is inversely proportional to the switching frequency in the ZVS region. The output voltage can be regulated by modulating the switching frequency. Figure 18 shows the typical circuit configuration for R_T pin, where the opto-coupler transistor is connected to the R_T pin to modulate the switching frequency.

The minimum switching frequency is determined as:

$$f^{\min} = \frac{5.2k\Omega}{R_{\min}} \times 100(kHz) \tag{1}$$

Assuming the saturation voltage of the opto-coupler transistor is 0.2V, the maximum switching frequency is determined as:

$$f^{\max} = \left(\frac{5.2k\Omega}{R_{\min}} + \frac{4.68k\Omega}{R_{\max}}\right) \times 100(kHz)$$
⁽²⁾

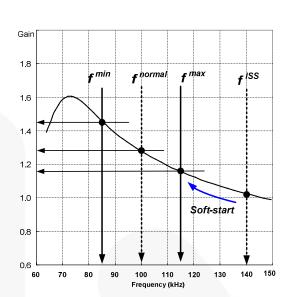
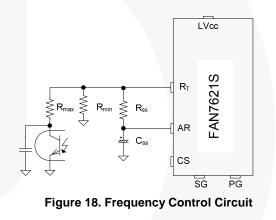


Figure 17. Resonant Converter Typical Gain Curve



To prevent excessive inrush current and overshoot of output voltage during startup, increase the voltage gain of the resonant converter progressively. Since the voltage gain of the resonant converter is inversely proportional to the switching frequency, the soft-start is implemented by sweeping down the switching frequency from an initial high frequency ($f^{(SS)}$) until the output voltage is established. The soft-start circuit is made by connecting R-C series network on the R_T pin, as shown in Figure 18. FAN7621S also has an internal soft-start of 3ms to reduce the current overshoot during the initial cycles, which adds 40kHz to the initial frequency of the external soft-start circuit, as shown in Figure 19. The initial frequency of the soft-start is given as:

$$f^{ISS} = (\frac{5.2k\Omega}{R_{\min}} + \frac{5.2k\Omega}{R_{SS}}) \times 100 + 40 \ (kHz)$$
(3)

It is typical to set the initial (soft-start) frequency two ~ three times the resonant frequency (f_0) of the resonant network.

The soft-start time is three to four times the RC time constant. The RC time constant is as follows:

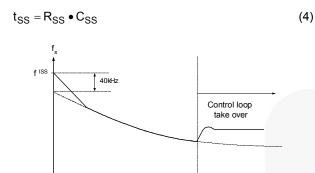


Figure 19. Frequency Sweeping of Soft-Start

time

4. Self Auto-restart: The FAN7621S can restart automatically even if a built-in protection is triggered with external supply voltage. As shown in Figure 20 and Figure 21; once any protections are triggered, M1 switch turns on and V-I converter is disabled. C_{SS} starts to be discharged until the V_{Css} across C_{SS} drops to V_{CssL} . Then all protections are reset, M1 turns off, and V-I converter resumes. The FAN7621S starts switching again with softstart. If the protections occur while V_{Css} is under V_{CssL} and V_{CssH} level, the switching is terminated immediately, V_{Css} continues to increase until reaching V_{CssH} , then C_{SS} is discharged by M1.

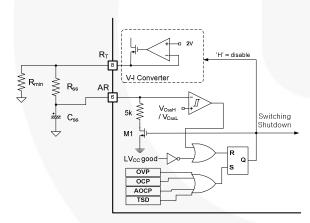


Figure 20. Internal Block of AR Pin

After protections trigger, FAN7621S is disabled during the stop-time, t_{stop} , where V_{Css} decreases and reaches to V_{CssL} . The stop-time of FAN7621S can be estimated as:

$$t_{stop} = C_{ss} \cdot \{ (R_{ss} + R_{min}) \parallel 5k\Omega \}$$
(5)

For the soft-start time, $t_{s/s}$ it can be set as Equation (4).

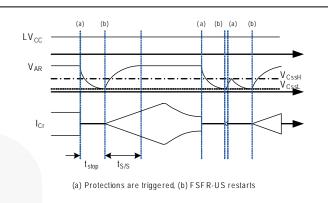


Figure 21. Self Auto-Restart Operation

5. Protection Circuits: The FAN7621S has several selfprotective functions, such as Over-Current Protection (OCP), Abnormal Over-Current Protection (AOCP), Over-Voltage Protection (OVP), and Thermal Shutdown (TSD). These protections are auto-restart mode protections, as shown in Figure 21.

Once a fault condition is detected, switching is terminated and the MOSFETs remain off. When LV_{CC} falls to the LV_{CC} stop voltage of 10V or the AR signal is HIGH, the protection is reset. FAN7621S resumes normal operation when LV_{CC} reaches the start voltage of 12.5V.

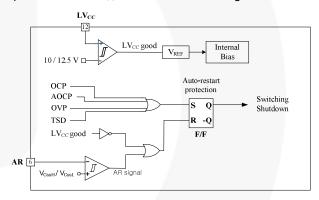


Figure 22. Protection Blocks

5.1 Over-Current Protection (OCP): When the sensing pin voltage drops below -0.58V, OCP is triggered and the MOSFETs remain off. This protection has a shutdown time delay of 1.5µs to prevent premature shutdown during startup.

5.2 Abnormal Over-Current Protection (AOCP): If the secondary rectifier diodes are shorted, large current with extremely high di/dt can flow through the MOSFET before OCP is triggered. AOCP is triggered without shutdown delay when the sensing pin voltage drops below -0.9V.

5.3 Over-Voltage Protection (OVP): When the LV_{CC} reaches 23V, OVP is triggered. This protection is used when auxiliary winding of the transformer to supply V_{CC} to the controller is utilized.

5.4 Thermal Shutdown (TSD): If the temperature of the junction exceeds approximately 130°C, the thermal shutdown triggers.

6. Current Sensing Using Resistor: FAN7621S senses drain current as a negative voltage, as shown in Figure 23 and Figure 24. Half-wave sensing allows low power dissipation in the sensing resistor, while full-wave sensing has less switching noise in the sensing signal.

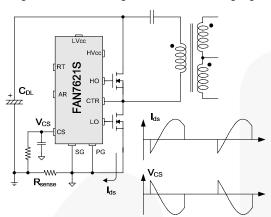
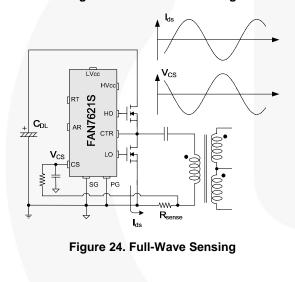


Figure 23. Half-Wave Sensing



7. PCB Layout Guidelines: Duty imbalance problems may occur due to the radiated noise from the main transformer, the inequality of the secondary-side leakage inductances of main transformer, and so on. It is one of the dominant reasons that the control components in the vicinity of R_T pin are enclosed by the primary current flow pattern on PCB layout. The direction of the magnetic field on the components caused by the primary current flow is changed when the high- and low-side MOSFET turns on by turns. The magnetic fields with opposite direction from each other induce a current through, into, or out of the R_T pin, which makes the turn-on duration of each MOSFET different. It is strongly recommended to separate the control components in the vicinity of R_T pin from the primary current flow pattern on PCB layout. Error! Reference source not found. shows an example for the duty-balanced case. The yellow and blue lines show the primary current flows when the lower-side and higherside MOSFETs turn on, respectively. The primary current does not enclose any component of controller.

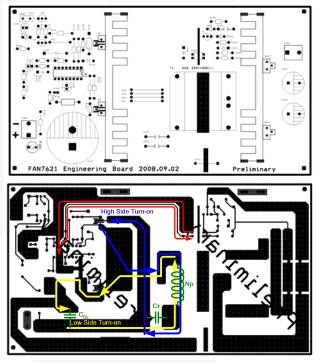
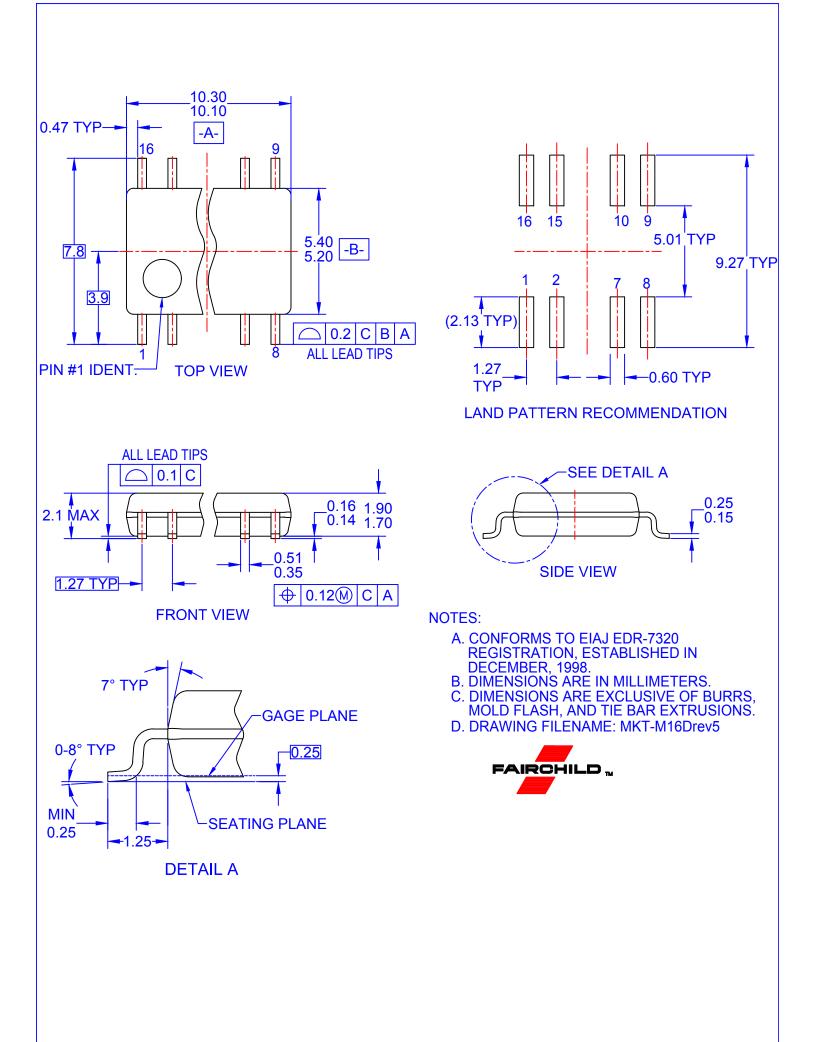


Figure 25. Example for Duty Balancing





* Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. TO OBTAIN THE LATEST, MOST UP-TO-DATE DATASHEET AND PRODUCT INFORMATION, VISIT OUR WEBSITE AT <u>HTTP://WWW.FAIRCHILDSEMI.COM</u>, FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

AUTHORIZED USE

Unless otherwise specified in this data sheet, this product is a standard commercial product and is not intended for use in applications that require extraordinary levels of quality and reliability. This product may not be used in the following applications, unless specifically approved in writing by a Fairchild officer: (1) automotive or other transportation, (2) military/aerospace, (3) any safety critical application – including life critical medical equipment – where the failure of the Fairchild product reasonably would be expected to result in personal injury, death or property damage. Customer's use of this product is subject to agreement of this Authorized Use policy. In the event of an unauthorized use of Fairchild's product, Fairchild accepts no liability in the event of product failure. In other respects, this product shall be subject to Fairchild's Worldwide Terms and Conditions of Sale, unless a separate agreement has been signed by both Parties.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Terms of Use

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Terms				
Datasheet Identification	Product Status	Definition		
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.		
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.		
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.		
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.		

Rev. 177